

Vishay General Semiconductor

Ultrafast Plastic Rectifier



FEATURES

- · Glass passivated chip junction
- Ultrafast reverse recovery time
- Low forward voltage drop
- · Low switching losses, high efficiency
- High forward surge capability
- Solder Dip 260 °C, 40 seconds
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer and telecommunication.

MECHANICAL DATA

Case: DO-201AD Epoxy meets UL 94V-0 flammability rating Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D E3 suffix for commercial grade Polarity: Color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	VALUE	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	600	V	
Maximum RMS voltage	V _{RMS}	420	V	
Maximum DC blocking voltage	V _{DC}	600	V	
Maximum average forward rectified current, 0.375" (9.5 mm) lead length at $T_L = 110 ^\circ\text{C}$	I _{F(AV)}	3.0	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	90	А	
Operating junction and storage temperature range	T _J , T _{STG}	- 40 to + 150	°C	
Reverse avalanche energy (8/20 µs surge)	E _{AR}	10	mJ	

MAJOR RATINGS AND CHARACTERISTICS IF(AV) 3.0 A VRRM 600 V IFSM 90 A trr 30 ns VF 1.6 V

150 °C

T_i max.



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Minimum reverse breakdown voltage	at 10 μA	V _(BR)	600	V
Maximum instantaneous forward voltage (1)	at 3.0 A	V _F	1.6	V
Maximum DC reverse current at rated DC blocking voltage		I _R	20	μΑ
Maximum reverse recovery time	at $I_F = 0.5 \text{ A}$, $I_R = 1.0 \text{ A}$, $I_{rr} = 0.25 \text{ A}$	t _{rr}	30	ns

THERMAL CHARACTERISTICS ($T_A = 25 \degree C$ unless otherwise noted)					
PARAMETER		SYMBOL	VALUE	UNIT	
Typical thermal resistance (1)	junction-to-ambient junction-to-lead	R _{θJA} R _{θJL}	30 8.0	°C/W	

Note:

(1) Pulse test: 300 μ s pulse width, 1 % duty cycle

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
31GF6-E3/54	1.13	54	1400	13" Diameter Paper Tape & Reel	
31GF6-E3/73	1.13	73	1000	Ammo Pack Packaging	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

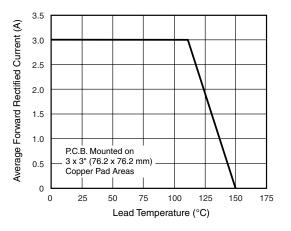


Figure 1. Maximum Forward Current Derating Curve

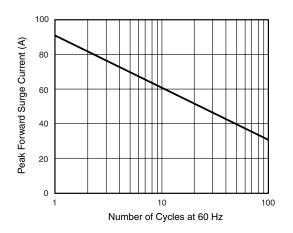


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



31GF6

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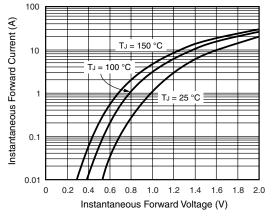


Figure 3. Typical Forward Voltage

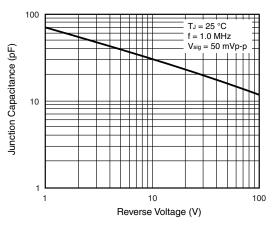


Figure 5. Typical Junction Capacitance

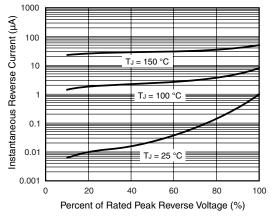
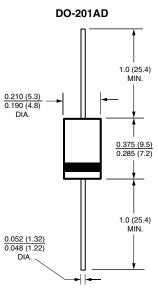


Figure 4. Typical Reverse Current

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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